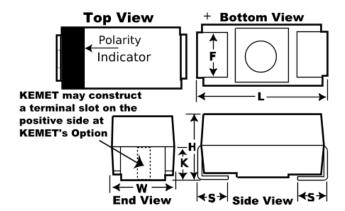


## T495C335M035ZTE5507280

Obsolete

Tantalum, MnO2 Tantalum, 3.3 uF, 20%, 35 VDC, SMD, Molded, Low ESR, Surge Robust, 550 mOhms, 6032, 2.8mm



Dimensions	
Footprint	6032
L	6mm +/-0.3mm
W	3.2mm +/-0.3mm
Н	2.5mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.2mm +/-0.1mm
K	1.8mm TYP

Packaging Specifications	
Packaging	T&R, 330mm
Packaging Quantity	3000

General Information	
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, Molded, Low ESR, Surge Robust
Features	Low ESR, Surge Robust
RoHS	Yes
Termination	Tin
AEC-Q200	No
Notes	Obsolete. Old Part Number [Obsolete] Was B45197A6335M306.

Specifications	
Capacitance	3.3 uF
Capacitance Tolerance	20%
Voltage DC	35 VDC (85C), 23.45 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
ESR	0.55 Ohms (100kHz)
Ripple Current	450 mAmps (25C), 405 mAmps (85C), 180 mAmps (125C)
Leakage Current	1.2 uA

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